Determinant Monte Carlo algorithms for dynamical quantities in fermionic systems



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We express the partition function as a series in the interaction (here *U*):

$$Z = \sum_{n} Z_{n} U^{n}$$

Diagrammatic MC algorithm: write Z_n as a sum of Feynman diagrams:

$$Z_n = \int dx_1 \dots dx_n \sum_{\text{Feynman diagrams } \mathcal{F}} \mathcal{F}(x_1, \dots, x_n) = \int dx_1 \dots dx_n \, \det(x_1, \dots, x_n)$$
MC sampling

What about dynamical quantities (Green's function, self-energy, ...)?

$$G_{n} = \int dx_{1} \dots dx_{n} \sum_{\text{conn. Feynman diagrams } \mathcal{F}} \mathcal{F}(x_{1}, \dots, x_{n})$$

$$\Sigma_{n} = \int dx_{1} \dots dx_{n} \sum_{\text{1PI Feynman diagrams } \mathcal{F}} \mathcal{F}(x_{1}, \dots, x_{n})$$

A. Moutenet et al., PRB 97, 085117 (2018)



Andreas Weh | Charge reconstruction in magnetic heterostructures: A real space dynamical mean-field approach



Equilibrium and Dynamical properties of magnetic clusters



Extended Monte Carlo Simulations

We run extended Monte Carlo simulation with two dynamical variables spins (Heatbath Algo), positions (Metropolis) both at T=0 and finite T.

$$H(\mathbf{S}_i, \mathbf{S}_j, d_{ij}) = -\frac{1}{2} \sum_{i,j} J(d_{ij}) \mathbf{S}_i \cdot \mathbf{S}_j + \frac{K}{2} \sum_{i,j} \left[\left(\frac{d^0}{d_{ij}} \right)^{12} - 2 \left(\frac{d^0}{d_{ij}} \right)^6 \right]$$
$$J(d_{ij}) = Je^{-\alpha \left(d_{ij} - d_{ij}^0 \right)} \qquad J < 0$$

Spin Dynamics





of memory effects?

SUPERVISOR: Dr Cedric Weber

100

50

0

Carla Lupo

Accurate first-principles description of the antiferromagnetic state of La₂CuO₄

<u>Christopher Lane</u>¹, James Furness², Ioana Buda¹, Yubo Zhang², Robert Markiewicz¹, Bernardo Barbiellini^{3,1}, Jianwei Sun², and Arun Bansil¹



Our computations correctly predict the key experimentally observed features of the electronic structure and magnetism of LCO/LSCO without invoking any *free parameters*.

Corentin Bertrand (CEA/INAC)

Quantum Monte-Carlo for nanoelectronics

Real time and out-of-equilibrium

Anderson Impurity Model / Kondo physics





A study of electron correlation effects in SrVO3 : Dynamical mean-field theory with a quasi-continuous time QMC solver

Engineering and Physical Sciences Research Council *E. Sheridan*, C.* Rhodes*, E. Plekhanov*, C. Weber* *King's College London, The Strand, WC2R 2LS London, UK



We are developing a fully integrated ab-intio package with the aim at the equation of state for strongly correlated systems.

Our approach

- \checkmark Linear Scaling in β .
- **Compact representations of** $G(\tau)$.
- Quasi-continuous via extrapolation in a polynomial basis.
- **Fully integrated into CASTEP**.
- MC, Hubbard I & IPT.

Future Goals

☐ Investigation into f-systems and high pressures.

- Phonons and Equation of State.
- Cerium volume collapse.

Case study: SrVO3

We are interested in the 3 t2g orbitals near the Fermi Level

$$H = H_{LDA}^{0} + \sum_{m} U_{mm} n_{m\uparrow} n_{m\downarrow} - \sum_{m\sigma} \mu n_{m\sigma}$$
$$+ \sum_{m < m'\sigma} U_{mm'} n_{m\sigma} n_{m'-\sigma}$$
$$+ \sum_{m < m'\sigma} (U_{mm'} - J_{mm'}) n_{m\sigma} n_{m'\sigma}$$

Our approach replicates the CT-QMC results at a fraction of the time











The role of interstitial hydrogen in $SrCoO_{2.5}$ antiferromagnetic insulator

Li Liang Department of Physics, Tsinghua University, China



N. Lu, P. Yu, et al. Nature, 2017: 546, 124



Crystal structures of $SrCoO_{2.5}$ (a) before and (b) after H doping. Red circle marks the lowest-energy position of the interstitial H locating in the hollow channel. (c) and (d), the corresponding DFT+U band structures.



(a) Charge difference induced by an interstitial H in different charge states. (b) The electrostatic potential induced by the H+ ion. Also shown is the ground-state AFM configuration of the Co ions. (c) Change of total energy ΔE by rotating different Co sites before and after H doping. The inset shows the ΔE -cos(θ) fitting.

Thanks

Importance of Many Body Effects in The Kernel of Hemocyanin Ligand Binding

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We perform first-principle quantum mechanical studies of dioxygen ligand binding to the hemocyanin protein. Electronic correlation effects in the functional site of hemocyanin are investigated using a state-of-the-art approach, which treats accurately local many body effects beyond the density functional theory (DFT), where the treatment of localised copper 3d electrons are studied using DFT+U and Dynamical Mean Field Theory (DMFT) for the first time.



Figure 1: The side-on $(\mu - \eta^2 : \eta^2)$ Cu₂O₂ 'butterfly' core of Hemocyanin.

Phase competition effect on superfluid stiffness in CDMFT



Superfluid stiffness vs doping with AFM + dSC for U = 12t: periodization vs cluster trace



Armitage, N., RevModPhys.82.2421 (2010)







Name: Paresh Chandra Rout

Title: Predicting emergent phenomena across different epitaxial strain regions in Sr-doped double-perovskite multiferroic Bi₂FeCrO₆ thin-films

Abstract: We explore the interplay between epitaxial strain and A-site hole doping in a thin-film of Bi_2FeCrO_6 (BFCO) structure by using first-principles DFT calculations. By substituting Bi with Sr in, namely Bi2–x Srx FeCr6 (x = 1, 0.5) under epitaxial strain, we show the possibility of mitigating the existing issues like anti-site defects and low magnetism in the BFCO thin-films. While hole doping induces novel functionalities such as polar half-metal, metal-to-insulator transitions, polar-to-nonpolar structural transitions and orbital orderings, the epitaxial strain plays a role in stabilizing these phases. Our work provides a plausible route to encode novel functionalities in double-perovskite oxide thin-films.

Metal-Insulator Transition in Oxide Heterostructures from DFT+DMFT

Sophie Beck & Claude Ederer, ETH Zürich, Switzerland

- emerging phenomena at oxide interfaces
- "material-by-design" principle
- complex interaction between structural and electronic degrees of freedom





Pavarini et al., New. J. Phys. 7, 188 (2005)

Materials:

 thin films and heterostructures of d¹, d² perovskites, Mott/band insulators, (correlated) metals

ETH zürich



Development of computational methods for the characterization of novel strongly correlated materials Uthpala Herath - West Virginia University, USA Email: ukh0001@mix.wvu.edu

International Summer School on Computational Quantum Materials May 27th to June 8th Sherbrooke, Québec

Project Goals

- To establish a user friendly software framework for investigating electronic, vibrational and elastic properties of strongly correlated materials using first-principles methods from DFT to DMFT.
- To investigate the evolution of strongly correlation for several complex materials such as Heusler alloys.



Crystal Structure and Chemical Composition

DFT+GGA Convergence of Parameters





Energetics and Relaxation







Phonon dispersion

Proposed Materials



Heusler Alloy prototypes:

- e.g.-
- CuMnSb
- Ni₂MnAl
- Co₂VGa
- MnFeGa
- MnPtGa



- Interesting magnetic ordering
- Magnetic shape memory effect
- Giant magnetic caloric effect

-> magnetic refrigeration



To be continued...



Development of computational methods for the characterization of novel strongly correlated materials

Uthpala Herath(1), Aldo H. Romero(1), Hyowon Park(2) (1) West Virginia University, (2) University of Illinois at Chicago International Summer School on Computational **Quantum Materials** May 27th to June 8th Sherbrooke, Québec

Project Goals

- To establish a software framework for investigating electronic, vibrational and elastic properties of stronlgy correlated materials using first-principles methods from DFT to DMFT.
- To develop a user-friendly and open-source DFT+DMFT code with various features based on effcient DFT implmentations.

Introduction			Proposed Materials		
 Motivation: Strongly Correlated Materials 3d Af orbitals are localized 	 Pansity functional theory (DFT) DFT has been a powerful first-principles method for weakly correlated materials. Currently available DFT codes has different interfaces for inputs, therefore it is difficult for users to take advantage of various features of different DFT codes. 	Overview: Crystal Structure and Chemical Composition	We are interested in:		
- SU,41 OIDITAIS are localized.		DFT+GGA Convergence of Parameters DFT+Hybrid \rightarrow DFT+U \rightarrow DMFT+DFT	 Materials with strong correlation effects to which 	Perovskite prototypes	



Application to the study of strongly correlated materials usually is not very accurate, therefore more advanced method beyond DFT is essential to treat the correlation problem. However, different choices of correlated orbitals, interaction parameters, and different levels of approximations to solve correlation problem have been the bottleneck of beyond DFT methods.

Partial occupations of of d- and/or f- orbitals lead to strong electronic correlations. Novel phenomena of strongly correlated materials include magnetism, high-temperature superconductivity, colossal magnetoresistance, heavy fermion systems, metal to insulator transitions (Mott insulator), and thermo-magnetism.

Theory: Dynamical Mean Field Theory

- \succ Within DFT, the correlation energy functional is crudely approximated. 1) We do not know the exact form of the correlation energy functional.
- 2) The dynamical correlation effect is ignored since the DFT functional is based on a static charge density.
- > Dynamical mean field theory (DMFT) : One defines a Free energy functional using a time-dependent and local Green's function G.
- $G_{i\sigma}$ $(t-t') \equiv -\langle C_{i\sigma}(t) C_{i\sigma} \dagger (t') \rangle$
- Advantages of DMFT:
- 1) The lattice problem can be mapped onto a local Anderson impurity problem hybridized to a self-consistently determined bath.
- 2) The impurity problem can be numerically solved in a non-perturbative way using quantum Monte Carlo and capture both itinerant and localized nature of electrons. 3) The DMFT calculation scales as O(N) where N is the number of the correlated



both d- and f- orbitals can contribute ex) Gd, LaNiO3



DFT+DMFT spectra can be directly compared to experimental photoemission spectroscopy data of real systems



Outline of new code

Methodology



Schematic flow diagram of the full charge-self-consistent DFT+DMFT



Features of our DFT+DMFT code

1) Various free-license DFT codes are available for DFT+DMFT simulations and





Dynamical mean field theory Impurity solver : CTQMC

Characterization of Strongly Correlated Materials : Band structure, DOS, Total energy, Atomic forces, Magnetic susceptibility, ...

same correlated basis sets (Maximally localized Wannier function) are used to obtain DMFT solutions to minimize the ambiguity of different DFT codes and to perform fair comparisons.

- 2) The DMFT part of the code scales linearly with the number of correlated atoms.
- 3) Interaction parameters U and J are obtained using the linear-response constrained DFT method.
- 4) Band structure, total energy, atomic force calculations are currently being implemented.
- 5) Other post-processing codes are also interfaced including Wannier90, phonopy,...

Proof of concept



DFT+DMFT bandstructure of LaNiO₃ compared to DFT bands (green) (left) and Metal-insulator and structural phase

diagram computed using charge self-consistent DFT+DMFT as a function of volume and the series of rare-earth ions

The interface



The structural diagram of the interface (left) and the current state of the program (top)



The VASP+DMFT interface has been implemented.

• The interface of DMFT with Siesta, QE, Abinit and ELK is currently being implemented.

A GUI version of the program will be implemented in the future.

Conclusions

(right).

- DFT is not suitable for studying electronic structure and energetics of strongly correlated materials.
- DFT+DMFT has been a powerful method but existing implementations are based on licensed DFT codes such as Wien2K.
- We implement a user-friendly and public DFT+DMFT code based on various freelicensed DFT programs by adopting the Wannier function as correlated orbitals.
- Our implementation can be linearly scalable (O(N)) for large-scale correlated systems by interfacing DMFT to efficient DFT codes such as Siesta.

Acknowledgements

This work was supported by the NSF OAC-1740111 and DOE DE-SC0016176 projects

Future work

- Implementation of the interatomic forces [5,6] within DFT+DMFT and extend the functionality to calculate phonons and stress of strongly correlated materials.
- Two-particle susceptibility calculations including the optical conductivity and the magnetic susceptibility.
- Fermi surface calculations.

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Diagrammatic Monte Carlo technique for frustrated spin system



Ab initio study of cross-interface electron-phonon couplings in FeSe thin films on SrTiO₃ and BaTiO₃

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Coupling function $|g(\mathbf{k}, \mathbf{q})|^2$ in the first Brillouin zone as a function of **k**. Left: $\mathbf{q} = (0,0)$. Right: $\mathbf{q} = (0,\frac{\pi}{64})$ and $400 \times |g(\mathbf{k},\mathbf{q})|^2$.

- ✤ Monolayer FeSe thin film on STO or BTO substrates has superconducting $T_c \sim 60 - 70$ K.
- Replica energy bands seen in ARPES spectra indicate a strong forwardfocused electron-phonon coupling g(k, q) peaked at small |q|.
- ★ We find from *ab initio* calculation that for the oxygen polar mode with mode energy Ω~100 meV, $g(\mathbf{k}, |\mathbf{q}| > \frac{\pi}{64}) \approx 0$, consistent with a forward-focused electron-phonon coupling.



Identification of intrinsic surface defects in a thin PtSe₂ film from first-principles

Yichul Choi, Fazel Baniasadi, Husong Zheng, Chenggang Tao, and Kyungwha Park Department of Physics, Virginia Tech





Theoretical Prediction of Oxygen-functionalized Mixed MXene as Topological Insulator **Mechanical Engineering** Zeeshan Ahmad^{*}, Venkat Viswanathan⁺ **Carnegie Mellon** Department of Mechanical Engineering, Carnegie Mellon University Email: *azeeshan@cmu.edu, +venkvis@cmu.edu





surrounded by a top layer of W atoms (pink) and a bottom layer of Mo atoms (gray). The red atoms are oxygens as functional group attached to M_1M_2Xene



Phase Transition from Topological to Trivial Insulator

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ACKNOWLEDGEMENTS

